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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re patent application of

Geiss, et al.

Serial No.: 10/711,482

Group Art Unit: 2811

Filed: Sep. 21, 2004

Examiner: Unknown

For: SiGe Heterojunction Bipolar Transistor (HBT) and Method of Fabrication

Assistant Commissioner of Patents

Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to Applicant's duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following documents listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. A copy of the listed documents are provided herewith for the convenience of the Examiner.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the Applicant is aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 09-0456.

Respectfully submitted,

Anthony J. Canale

Registration No. 51,526

International Business Machines Corporation Intellectual Property Law - Zip 972E 1000 River Street Essex Junction, VT 05452

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) BUR920040004US1 In Re Application Of: Peter Geiss, Alvin Joseph, Rajendran Krishnasamy, Xuefeng Liu Application No. Customer No. Group Art Unit Confirmation No. Filing Date Examiner 5481 10/711,48 Sep. 21, 2004 24241 2811 Title: SiGe Heterojuncton Bipolar Transistor (HBT) and Method of Fabrication Address to: **Commissioner for Patents** P.O. Box 1450 Alexandria, VA 22313-1450 37 CFR 1.97(b) The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114. 37 CFR 1.97(c) 2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of: ☐ the statement specified in 37 CFR 1.97(e); OR ☐ the fee set forth in 37 CFR 1.17(p).

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) BUR920040004US1 In Re Application: Peter Geiss, Alvin Joseph, Rajendran Kpishnasamy, Xuefeng Liu Examina 2 7 2008 Customer No. **Group Art Unit** Confirmation No. Application No. Filing Date 5481 24241 2811 10/711,48 Sep. 21, 2004 Title: SiGe Heterojuncton Bipolar Transistor (HBT) and Method of Fabrication Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p)) is attached. A check in the amount of ☑ The Director is hereby authorized to charge and credit Deposit Account No. ○9 -0456 as described below. Charge the amount of Credit any overpayment. Charge any additional fee required. □ Payment by credit card. Form PTO-2038 is attached. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038. Certificate of Mailing by First Class Mail Certificate of Transmission by Facsimile* I hereby certify that this correspondence is being deposited I certify that this document and authorization to charge deposit with the United States Postal Service with sufficient postage account is being facsimile transmitted to the United States as first class mail in an envelope addressed to Patent and Trademark Office (Fax. No. "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on an 21 2005 (Date) Signature of Person Mailing Correspondence Signature ratricia Typed or Printed Name of Person Mailing Certificate Typed or Printed Name of Person Signing Certificate *This certificate may only be used if paying by deposit account. Dated: 0/21/2005 cc:

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